

X3-Class HiPerFET™ **Power MOSFET**

IXFP36N20X3M

= 200V= 36A \leq 45m Ω

(Electrically Isolated Tab)

N-Channel Enhancement Mode



	OVERMOLDED TO-220
igs	G
V	D Isolated Tab

G = Gate	D = Drain
S = Source	

Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	$T_J = 25^{\circ}C \text{ to } 150^{\circ}C$	200	V	
$V_{\scriptscriptstyle DGR}$	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M Ω	200	V	
V _{GSS}	Continuous	±20	V	
V _{GSM}	Transient	±30	V	
I _{D25}	$T_{\rm C} = 25^{\circ}$ C, Limited by $T_{\rm JM}$	36	Α	
I _{DM}	$\rm T_{_{\rm C}}$ = 25°C, Pulse Width Limited by $\rm T_{_{\rm JM}}$	50	Α	
I _A	$T_{c} = 25^{\circ}C$	18	Α	
E _{AS}	$T_{c} = 25^{\circ}C$	300	mJ	
dv/dt	$I_{_{\mathrm{S}}} \leq I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \leq V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \leq 150^{\circ}\mathrm{C}$	20	V/ns	
P_{D}	T _C = 25°C	36	W	
T _J		-55 +150	°C	
T_{JM}		150	°C	
T _{stg}		-55 +150	°C	
T _L	Maximum Lead Temperature for Soldering	300	°C	
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C	
V _{ISOL}	50/60 Hz, 1 Minute	2500	V~	
M _d	Mounting Torque	1.13 / 10	Nm/lb.in	
Weight		2.5	g	

Features

- International Standard Package
- Plastic Overmolded Tab
- Low R_{DS(ON)} and Q_G
 Avalanche Rated
- 2500V~ Electrical Isolation
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

			teristic \ Typ.	Values Max.
BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	200		V
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_{D} = 500\mu A$	2.5		4.5 V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100 nA
I _{DSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			5 μA 100 μA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 18A, Note 1$		38	45 mΩ





Symbol Test Conditions		Characteristic Values		
(T _J = 25°C, Unless Otherwise Specified)		Min.	Тур.	Max
g_{fs}	$V_{DS} = 10V, I_{D} = 18A, \text{ Note 1}$	16	26	S
R _{Gi}	Gate Input Resistance		1.6	Ω
C _{iss}			1425	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		280	pF
C _{rss}			1.2	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		130	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		400	pF
t _{d(on)}	Resistive Switching Times		19	ns
t _r	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 18A$		30	ns
t _{d(off)}	$R_{\rm g} = 30\Omega$ (External)		54	ns
t,)	Tig = 5512 (External)		20	ns
Q _{g(on)}			21	nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 18A$		8	nC
Q _{gd}			7	nC
R _{thJC}				3.5 °C/W
R _{thcs}			0.50	°C/W

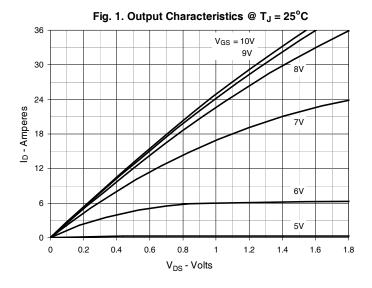
SYM	INCHES		MILLIN	1ETERS
2114	MIN	MAX	MIN	MAX
Α	.177	.193	4.50	4.90
A1	.092	.108	2.34	2.74
A2	.101	.117	2.56	2.96
b	.028	.035	0.70	0.90
b1	.050	.058	1.27	1.47
С	.018	.024	0.45	0.60
D	.617	.633	15.67	16.07
E	.392	.408	9.96	10.36
е	.100 BSC		2.54 BSC	
Н	.255	.271	6.48	6.88
L	.499	.523	12.68	13.28
L1	.119	.135	3.03	3.43
ØΡ	.121	.129	3.08	3.28
Q	.126	.134	3.20	3.40

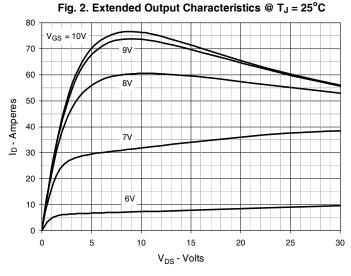
Source-Drain Diode

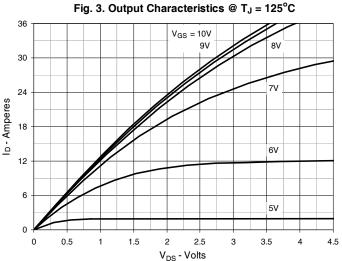
Symbol Test Conditions			Characteristic Values			
$(I_J = 25^{\circ}C)$, Unless Otherwise Specified)	Min.	Тур.	Max		
I _s	$V_{GS} = 0V$			36	Α	
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			144	Α	
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V	
t _{rr}	$I_{\rm F} = 18A$, -di/dt = 100A/ μ s		75		ns	
Q _{RM}	$V_{\rm p} = 100 \rm V$		230		nC	
I _{RM}	v _R = 100 v		6		A	

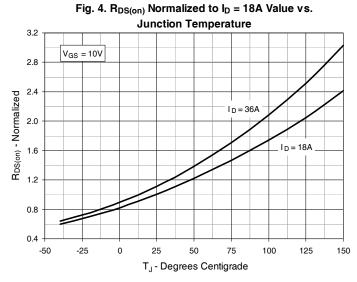
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

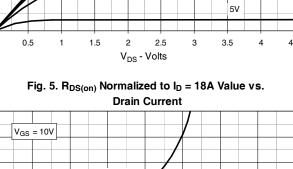


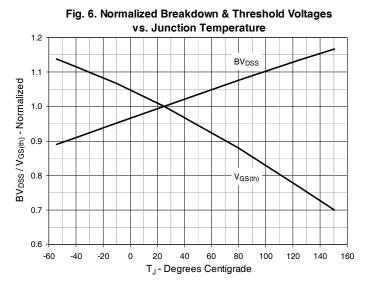


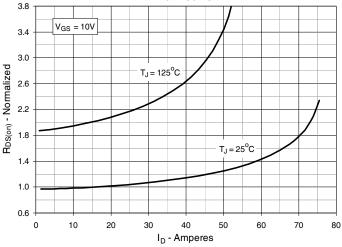




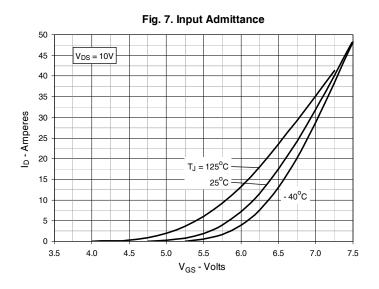


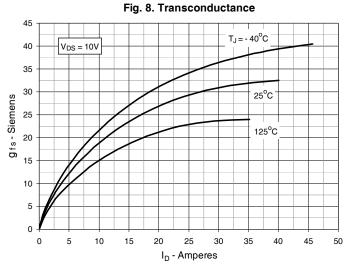


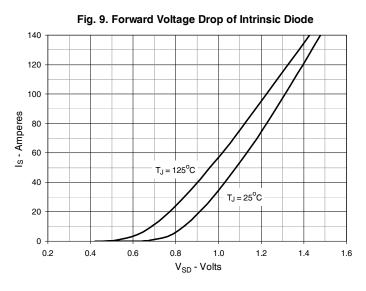


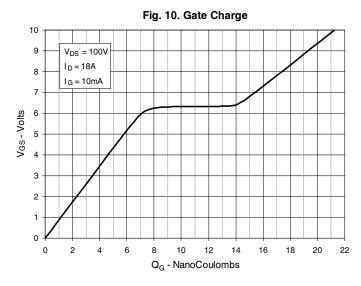


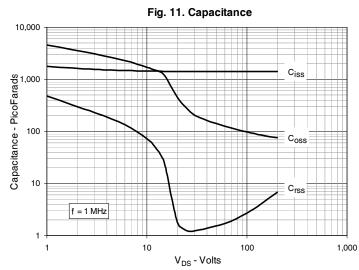


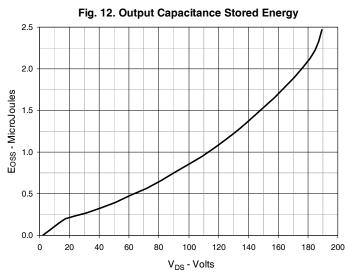




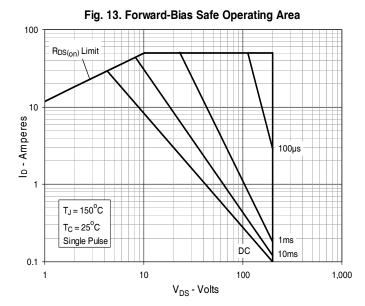


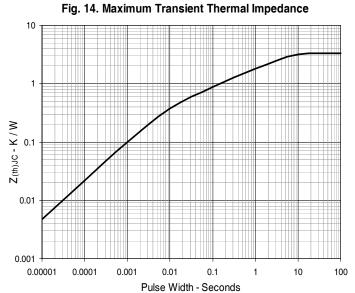






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